

<b>SANYO</b>	No.1419B	<b>2SK443</b>
		N-Channel Junction Silicon Field-Effect Transistor

**Video Camera First-Stage Applications**

**Features**

- Large  $|y_{fs}|$ .
- Small Ciss.
- Very low noise figure.
- Very small-sized package permitting 2SK443-applied sets to be small-sized.

**Absolute Maximum Ratings at Ta = 25°C**

			unit
Drain-to-Source Voltage	V <sub>DSS</sub>	15	V
Gate-to-Drain Voltage	V <sub>GDS</sub>	-15	V
Gate Current	I <sub>G</sub>	10	mA
Drain Current	I <sub>D</sub>	50	mA
Power Dissipation	P <sub>D</sub>	200	mW
Junction Temperature	T <sub>J</sub>	125	°C
Storage Temperature	T <sub>stg</sub>	-55 to +125	°C

**Electrical Characteristics at Ta = 25°C**

			min	typ	max	unit
Gate-to-Drain Breakdown Voltage	V <sub>(BR)GDS</sub>	I <sub>D</sub> = 10 μA, V <sub>DS</sub> = 0	-15			V
Common-Source Gate Cutoff Current	I <sub>GSS</sub>	V <sub>GS</sub> = -10V, V <sub>DS</sub> = 0			-1.0	nA
Gate-to-Source Cutoff Voltage	V <sub>GS(off)</sub>	V <sub>DS</sub> = 5V, I <sub>D</sub> = 100 μA	-0.9	-2.0		V
Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> = 5V, V <sub>GS</sub> = 0	5.0*		38.0*	mA
Forward Transfer Admittance	y <sub>fs</sub>	V <sub>DS</sub> = 5V, V <sub>GS</sub> = 0, f = 1kHz	20	30		mS
Input Capacitance	Ciss	V <sub>DS</sub> = 5V, V <sub>GS</sub> = 0, f = 1MHz		9.0		pF
Reverse Transfer Capacitance	Crss	V <sub>DS</sub> = 5V, V <sub>GS</sub> = 0, f = 1MHz		2.8		pF
Noise Figure	NF	V <sub>DS</sub> = 5V, R <sub>g</sub> = 1kΩ, I <sub>D</sub> = 1mA, f = 1kHz		1.5		dB

\* The 2SK443 is classified by I<sub>DSS</sub> as follows (unit : mA) :

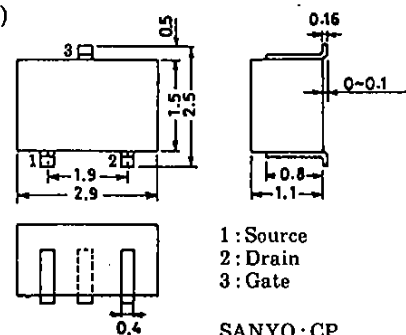
5.0	5	12.0	10.0	6	24.0	16.0	7	38.0
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(Note) Marking : AJ

I<sub>DSS</sub> rank : 5, 6, 7

**Package Dimensions 2050A**

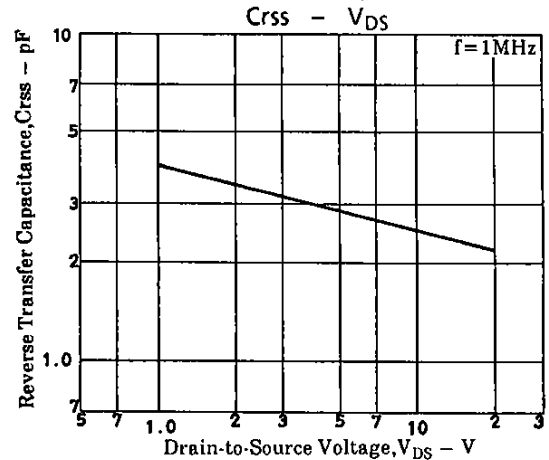
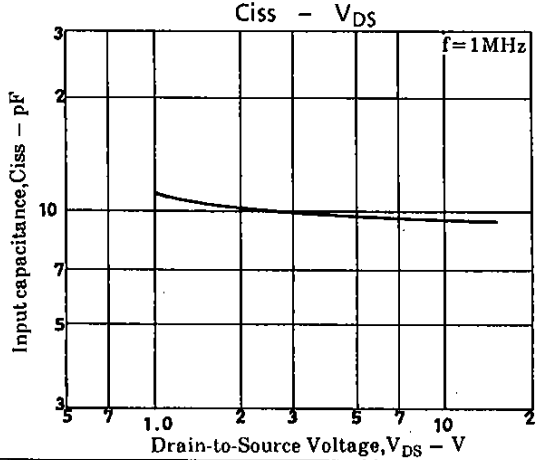
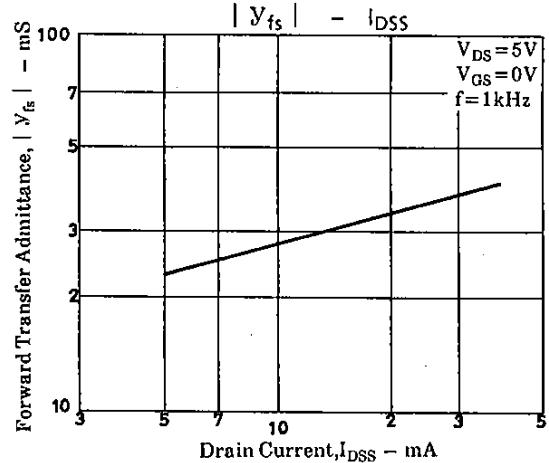
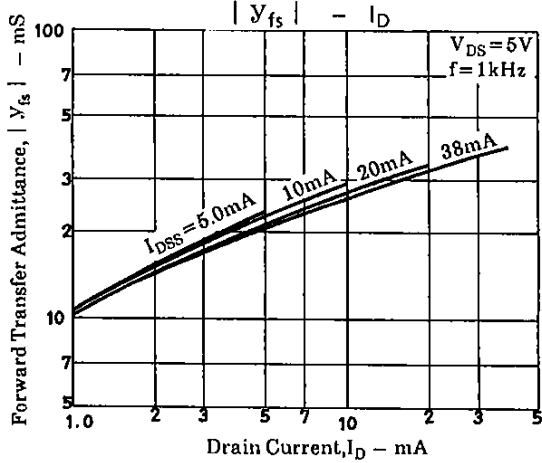
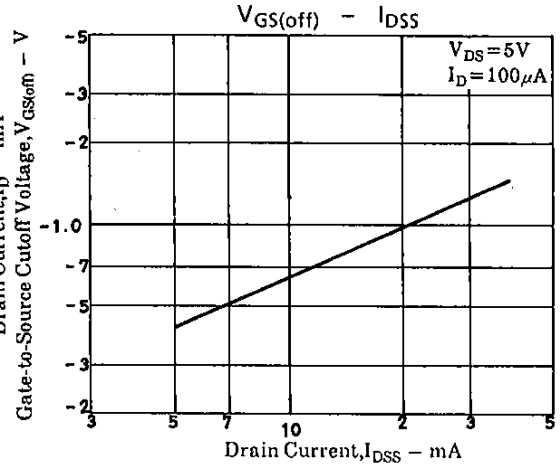
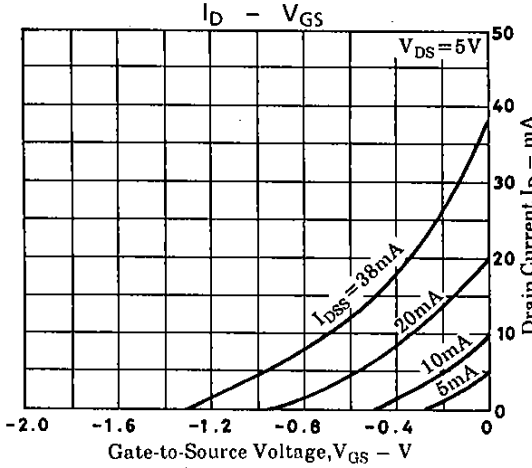
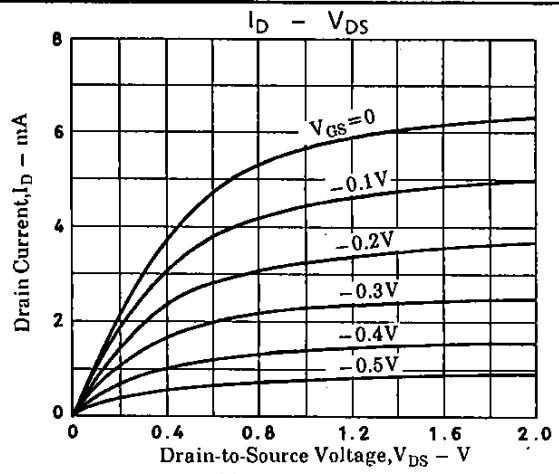
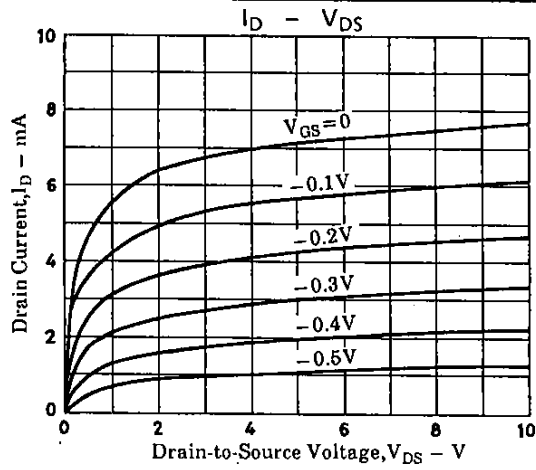
(unit : mm)

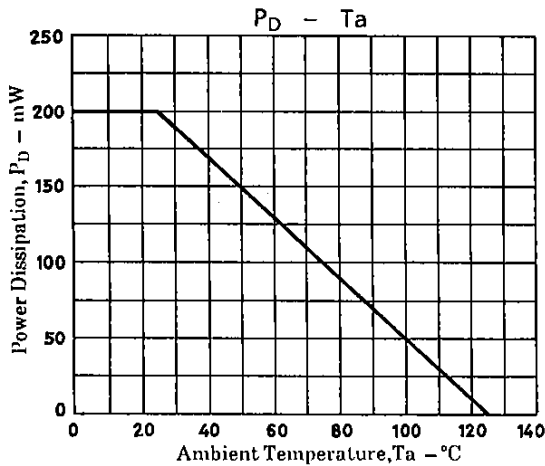
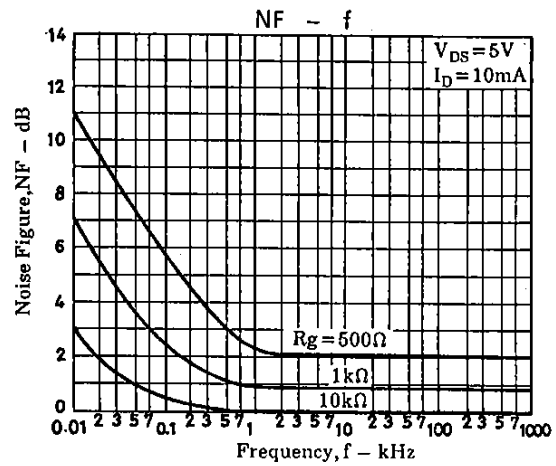
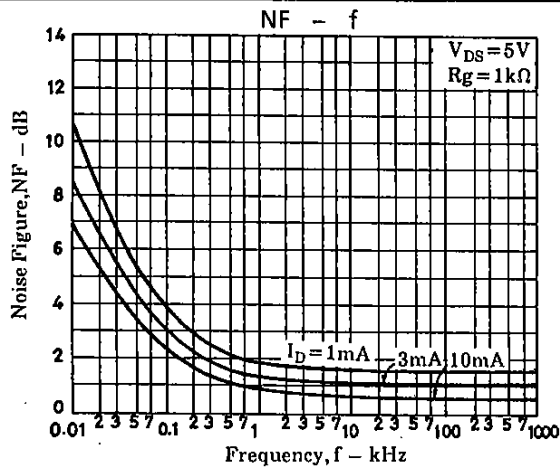


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